

# UNISONIC TECHNOLOGIES CO., LTD

## MPSA113

## NPN EPITAXIAL SILICON TRANSISTOR

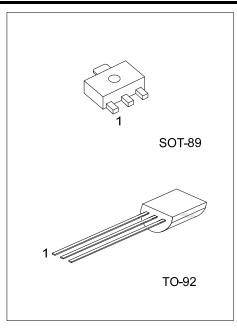
# DARLINGTON TRANSISTOR

#### DESCRIPTION

The UTC **MPSA113** is a Darlington transistor.

#### FEATURES

\* Collector-Emitter Voltage: V<sub>CES</sub> = 30V



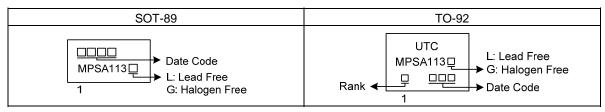
#### ORDERING INFORMATION

| Ordering Number                                       |                | Deekege | Pin Assignment |   |   | Dealing   |  |
|-------------------------------------------------------|----------------|---------|----------------|---|---|-----------|--|
| Lead Free                                             | Halogen Free   | Package | 1              | 2 | 3 | Packing   |  |
| MPSA113L-AB3-R                                        | MPSA113G-AB3-R | SOT-89  | В              | С | Е | Tape Reel |  |
| MPSA113L-T92-B                                        | MPSA113G-T92-B | TO-92   | Е              | В | С | Tape Box  |  |
| MPSA113L-T92-K                                        | MPSA113G-T92-K | TO-92   | Е              | В | С | Bulk      |  |
| Noto: Din Assignment: P: Pase C: Collector E: Emitter |                |         |                |   |   |           |  |

Note: Pin Assignment: B: Base C: Collector E: Emitter

| MPSA113G-AB3-R    |                                                 |
|-------------------|-------------------------------------------------|
| T (1)Packing Type | (1) B: Tape Box, K: Bulk, R: Tape Reel          |
| (2)Package Type   | (2) AB3: SOT-89, T92: TO-92                     |
| (3)Green Package  | (3) G: Halogen Free and Lead Free, L: Lead Free |
|                   |                                                 |

#### MARKING



## NPN EPITAXIAL SILICON TRANSISTOR

#### ABSOLUTE MAXIMUM RATING (Operating temperature range applies unless otherwise specified.)

| PARAMETER                      | SYMBOL              | RATINGS    | UNIT |
|--------------------------------|---------------------|------------|------|
| Collector-Base Voltage         | V <sub>CBO</sub> 30 |            | V    |
| Collector-Emitter Voltage      | V <sub>CES</sub> 30 |            | V    |
| Emitter-Base Voltage           | V <sub>EBO</sub>    | 10         | V    |
| Collector Dissipation(Tc=25°C) | P <sub>C</sub> 625  |            | mW   |
| Collector Current              | Ι <sub>C</sub>      | 500        | mA   |
| Junction Temperature           | TJ                  | +150       | ٥C   |
| Storage Temperature            | T <sub>STG</sub>    | -55 ~ +150 | °C   |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ELECTRICAL CHARACTERISTICS (TJ=25°C, unless otherwise specified)

|                                         | 1                    | +                                                  |       |     |     | i    |
|-----------------------------------------|----------------------|----------------------------------------------------|-------|-----|-----|------|
| PARAMETER                               | SYMBOL               | TEST CONDITIONS                                    | MIN   | TYP | MAX | UNIT |
| Collector-Emitter Breakdown<br>Voltage  | BV <sub>CES</sub>    | I <sub>C</sub> =100μA, I <sub>B</sub> =0           | 30    |     |     | V    |
| Collector Cut-Off Current               | I <sub>CBO</sub>     | $V_{CB}=30V, I_{E}=0$                              |       |     | 100 | nA   |
| Emitter Cut-Off Current                 | I <sub>EBO</sub>     | V <sub>EB</sub> =10V, I <sub>C</sub> =0            |       |     | 100 | nA   |
| DC Current Gain                         | h <sub>FE</sub>      | V <sub>CE</sub> =5V, I <sub>c</sub> =100mA         | 30000 |     |     |      |
| Collector-Emitter Saturation<br>Voltage | V <sub>CE(SAT)</sub> | I <sub>C</sub> =100mA, I <sub>B</sub> =0.1mA       |       |     | 1.5 | V    |
| Base-Emitter on Voltage                 | V <sub>BE(ON)</sub>  | V <sub>CE</sub> =5V, I <sub>C</sub> =100mA         |       |     | 2.0 | V    |
| Current Gain Bandwidth Product          | f <sub>T</sub>       | V <sub>CE</sub> =5V,I <sub>C</sub> =10mA, f=100MHz | 125   |     |     | MHz  |

Note: Pulse test: Pulse Width<300µs, Duty Cycle=2%



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